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Accurate semiempirical analytical formulas for spontaneous polarization by crystallographic parameters of SrTiO3-BaTiO3 system by ab initio calculations

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https://hdl.handle.net/2324/1961330

出版情報: Computational Materials Science. 158, pp.315-323, 2019-02-15. Elsevier

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semiempirical

Accurate

Computational Materials Science 158, 315–323 (2019). https://doi.org/10.1016/j.commatsci.2018.11.043

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analytical formulas for

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Spontaneous polarizations (P_S 's) of BaTiO₃ and SrTiO₃ under various conditions are calculated ab

initio using different exchange-correlation functionals. The extensive theoretical sets of $P_{\rm S}$ vs. ion positions

are found to lie on a single curve, despite the chemical differences and the wide variations of $P_{\rm S}$ and lattice

parameters. This uncovers accurate simple analytical formulas of P_S of SrTiO₃-BaTiO₃ system expressed by

ion positions; a single formula predicts both macroscopic and atomic-scale P_S of SrTiO₃, BaTiO₃ and

SrTiO₃-BaTiO alloys. The accuracy of the formula is demonstrated by the application to experiments,

BaTiO₃-SrTiO₃ (-CaTiO₃) alloys, $Sr_4Ti_4O_{12}$ with P_S // a-axis, a parallel domain, and a headon domain. In

addition, the present results verify empirically that oxygen displacement is the primary identifier and the

origin of P_S of SrTiO₃ and BaTiO₃ and indicate that BaTiO₃ and SrTiO₃ may transforms into new state by an

extremely large strain, e.g., -3%. Furthermore, the earlier prediction of headon domain without aid of defects

was confirmed. The present procedures for finding formulas can be applied to other materials.

Keywords: polarization, TEM, atom position, strain, crystallographic estimation, domain

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1. Introduction

Electrically reversible spontaneous polarization P_S is the principal property of ferroelectrics [1]. P_S depends on chemical composition, lattice parameters, growth processes, and ambient conditions such as temperature and strain. Although P_S is estimated by polarization loop measurements or pyroelectric current [1], these measurements cannot work occasionally because of high conductance, strong pinning, or small sizes. In such cases, crystallographic estimation of P_S can be useful and effective for ultrahigh speed measurements of P_S . Moreover, the value of P_S varies within a given material due to domains, surface, interface with other materials, electric field, and strain. In these cases, the estimation of local P_S or atomic scale P_S , is essential for the understanding ferroelectric properties. Such measurements are frequently performed through the identifications of ion positions by transmission electron microscopy (TEM) [2].

The ferroelectricity of ABO₃-type perovskite oxides (A: A-site ion, B: B-site ion, O: oxygen) are conventionally explained by displacement of ions from the positions of a centrosymmetric structure (Fig. 1), where the displacement patterns are described by Slater [3], Last [4] and Axe mode [5]. These displacements in BaTiO₃ are considered to occur in a cage formed by Ba ions [6], which suggests that the ferroelectricity can be described by the displacements of Ti and O ions. Consequently, the position of B-site ion such as Ti and Zr is used to represent local P_S [7]. On the other hand, Bilz et al. [8] have successfully explained the ferroelectricity by O-ion displacements.

Indeed, we found that the plot of P_S vs. the distance between Ti and O ion of BaTiO₃ under various strains calculated with several exchange-correlation (XC) functionals lay precisely on a single curve, despite widely varying P_S [9]. The present paper reveals that all the sets of P_S and certain ion positions of prototypical ferroelectrics BaTiO₃ and SrTiO₃ lie precisely on a single curve, despite chemical difference, structural difference, and widely varying P_S . This is probably due to the similarity between BaTiO₃ and SrTiO₃ that the bonding between A-site ion and Ti is weak [6].

The variations of P_S were mostly due to some ion positions. Therefore, these plots uncover analytical expressions of P_S by ion positions, e.g., given by experiments, of which validity is confirmed in Sec. 4. These examinations show also that the oxygen position is more appropriate than the Ti position as an identifier of P_S consistently with Bilz et al. [8], which is more evident in SrTiO₃ than in BaTiO₃. The present

paper shows also the distance between Ti and O as the primary order parameter.

2. Computational method

Under stress-free condition, BaTiO₃ is tetragonal (C_{4v}^{1}) at room temperature (RT) (Table 1 and Fig. 1(a)). RT-phase and low-temperature (low-T) phase SrTiO₃ under stress-free condition are cubic (O_{h}^{1}) and tetragonal (O_{4h}^{18}), respectively [10, 11]. The RT-phase SrTiO₃ can be referred to SrTiO₃ with the antiferro-distortive (AFD) rotation angle (φ) = 0.

As for ferroelectric distortions, small uniform displacements of ions // c-axis, i.e., Slater-mode-like-displacements // c-axis, are applied as an initial perturbation for P_S except for the calculations in Sec. 4 (Table 2). Consequently, all these phases are tetragonal under biaxial inplane-stress (Table 1).

The unit-cell of low-T, i.e., 105K phase SrTiO₃ consists of 20 atoms [10] (Table 1), but the results of low-T phase SrTiO₃ are presented in pseudo cubic unitcell [11] (Fig. 1(b)). That is, all the results are presented for 5-atom unit cell, and P_S // c-axis except for two data in Sec. 4. The suffix "pc" stands for pseudo cubic unitcell. For example, we use [100]_{pc} for the a-axis of pseudo cubic unitcell.

The XC functionals [12-19] used in the present calculations are listed in Table 3. Although the XC functionals used for each data point are shown in legends of Figs. 3-6, the distinction of the XC functionals is unnecessary in the present work. In HSE (HSE06) [18], screening length μ was the default value (0.2 Å⁻¹) [16, 17]. TPSS + U agreed best with experiments of stress-free BaTiO₃ among the examined density functional +U approaches [9]. Here, both Liechtenstein [19] and Dudarev [20] schemes for TPSS+U without exchange term (J = 0) yielded mutually similar results. Therefore, the present paper reports the results with Liechtenstein scheme with J = 0 [9].

All calculations were performed using the projector augmented wave (PAW) method [21] as implemented in the Vienna *ab-initio* simulation package (Vasp) [22] with a plane wave energy cutoff of 650 eV. PAW potentials were chosen from those supplied by Vasp, so that the calculations with each XC functional agreed best with stress-free BaTiO₃. For the Brillouin-zone integration, Monkhorst-Pack meshes [23] of $6\times6\times6$ and $6\times6\times4$ were used in geometry relaxation and Berry phase calculation [24] of $P_{\rm S}$ for 5

and 20 atom unit cell, respectively. In the calculations in Sec. 4, Monkhorst-Pack meshes [23] of $8\times8\times4$, 6 $\times6\times2$, and $2\times6\times6$ were used for BaSrTiO₂O₆, a headon-domain, and a parallel domain, respectively. In the calculations of biaxially strained cases, geometry was fully relaxed under the constraint of fixed values of the *a*-axis lattice constant. After the geometry relaxations, all the calculated forces were always less than 0.001 eV/Å, except for the calculations of domains in Sec. 4 where a few atoms in the middle of each domain were fixed. These results were the same for denser mesh and more strict criteria of calculated forces. The effects of different PAW potentials and the screening length of HSE and HSEsol were much smaller than the difference of XC functionals. The consistency and accuracy of the present calculations were reported [9, 25].

The external strain u_{ext} for each phase is defined by $u_{\text{ext}} \equiv (a - a_0)/a_0$ where the theoretical a-axis lattice constant a_0 of the stress-free *minimum-free-energy* structure of each phase is calculated with each XC functional. The results below are for $-0.02 \le u_{\text{ext}} \le 0$ except for low-T phase SrTiO₃ and PBEsol calculations [9]: In the PBEsol calculations of BaTiO₃ and RT-phase SrTiO₃, $-0.04 \le u_{\text{ext}} \le 0$, while $-0.01 \le u_{\text{ext}} \le 0$ for low-T phase SrTiO₃. The φ dependence of low-T phase SrTiO₃ was calculated by PBEsol for $0^{\circ} \le \varphi \le 8^{\circ}$ [25] in Sec. 3. The illustrations of lattices and electron densities are drawn by VESTA [26]. Figure 1(a) shows the ion positions, where O1 and O2 stands for the oxygen ions in BaO (SrO) and TiO₂ plane, respectively.

3. Crystallographic estimation of P_S

3.1 Empirical formula of P_S from ab initio results

The electronic ground state of a given ferroelectric is calculable, when the positions of all the nuclei are determined, because the ground state electron density ρ is calculable from these positions (Fig.2). Therefore, P_S at the ground state, which is due to the non-centrosymmetric electron and ion distribution, is calculable, when the positions of all the nuclei are known.

From now, we focus on the periodic systems, i.e., infinite single crystals. In these cases, the positions of all the nuclei *in a unitcell* are sufficient for the preceding conclusions. Therefore, "ion positions" below means "all the ion positions in a unitcell" of a given ferroelectric material. According to the preceding conclusions, when both of the electron density ρ calculated for given ion positions and the calculation of polarization [24] are exact, P_S should be a well-defined single-valued function of ion positions f: $P_S = f$ (ion positions).

Indeed, we can assume that the calculations of both ρ and the polarization are accurate, because $P_{\rm S}$ calculated with all the XC functionals using experimental ion positions and lattice constants at 303K [27] agreed with the experimental $P_{\rm S}$ at 298 K (exp.: 0.25 C/m² [28]) [9]. In addition, $P_{\rm S}$ by different XC functionals was virtually the same when the crystallographic parameters were the same for all the calculations [9], although $P_{\rm S}$ varied with crystallographic parameters and XC functionals (Figs. 2 and 3). Therefore, the wide variations of the *ab initio* ρ and $P_{\rm S}$ in Figs. 2 and 3 are considered predominantly due to the difference in the estimation of the ion positions.

The next question is "how to find the function f or the most effective ion positions for P_S . Exemplarily in Fig. 3, each XC functional tends to yield specific deviations of crystallographic properties from ideal experimental ones, because it underestimates or overestimates some interactions depending on the approximations that each XC functional uses. Such deviations of ionic positions from ideal positions are considered to occur also locally in experiments owing to ambient temperature, defects and local strains. Therefore, the *ab initio* P_S *deviating from ideal experiments can be reinterpreted as exact calculations of* P_S *of the lattice deviating from ideal ones.* That is, we regard that all the *ab initio* P_S 's in the present calculations correspond exactly to some experimental situations or all the theoretical data in Figs. 3 - 6 represent some experiments.

In other words, the correlations between theoretical P_S and theoretical crystallographic properties correspond to those in experiments. Therefore, these correlations are used to identify the primary crystallographic property responsible for P_S that can be used for crystallographic identifications of P_S in experiments.

Consequently, the fitting to the data in each figure yields a semiempirical analytical formula f for P_S expressed by crystallographic parameters. If the selected crystallographic parameter represents the ion positions essential and necessary for P_S , all the data of P_S vs. of this parameter should be on a single curve. These arguments show that formulas of P_S expressed by crystallographic parameters (f's) exist for a given ferroelectric material.

Furthermore, in both $SrTiO_3$ and $BaTiO_3$, P_S is expected to be a function of Ti, O1 and O2 positions (Fig. 1(a)), because the contribution of Ba is shown to be small [6] and that of Sr is probably also small.

Therefore, an analytical formula f that works for both $SrTiO_3$ and $BaTiO_3$ may exist. Indeed, Fig. 6 shows that a single formula applicable for $SrTiO_3$ and $BaTiO_3$ exists, although it was unexpected.

3.2 Overview of results in Sec. 3

Section 3 presents the following results.

- Figure 2 illustrates how polar charge distributions appear and grow and how the difference between BaTiO₃ and SrTiO₃ originates.
- Figure 3 shows strain-dependence of P_S and ion positions, which suggests the primary ions responsible for P_S . In addition, Fig. 3 demonstrates exemplarily wide variations of P_S and ion positions due to XC functionals.
- Figure 4 examines conventionally accepted crystallographic parameters for P_S . These parameters are used frequently, because they are obtained by basic experiments.
- Figure 5 examines the representations of P_S by the position of a single ion, where Ti position is mostly used currently.
 - Figure 6 examines the positions of multiple ions for the representation of P_S .

In Figs. 3-6, the legends and captions explain XC functionals, e.g., PBEsol, and "_LT" in Figs. 4-6 shows a result for low-*T* phase SrTiO₃. However, they can be completely ignored for the understanding of the primary crystallographic parameters, while the results for BaTiO₃ and those for SrTiO₃ should be distinguished.

3.3 Dependence of P_S on crystallographic parameters

The electron density distribution ρ in Fig. 2 shows that Ti-O distance changes with $|u_{\text{ext}}|$ in both BaTiO₃ and RT-phase SrTiO₃, which explains the origin of the increase of P_{S} . These displacements change chemical bonding between ions, which was evident for $|u_{\text{ext}}| > 0.03$ as seen in Figs. 2(c), 2(f), 2(i) and 2(l). In particular, Ti-O2, Ti-O1 and Ba (Sr)-O1 bonding (Fig. 1(a)) were evidently fortified for $|u_{\text{ext}}| > 0.03$. Consequently, the bonding Ba, O1 and Ti are connected by strong bonding, and the charge distribution around Ti changes from spheres to pancakes as seen in the [110] planes (Figs. 2(f) and 2(l)).

Despite the clear difference in ρ at $u_{\text{ext}} = 0$ (Figs. 2(a), 2(d), 2(g) and 2(j)), ρ of BaTiO₃ and RT-phase

SrTiO₃ are mutually similar at these large strain (Figs. 2(c), 2(f), 2(i) and 2(l)). This is consistent with P_S and Δz_{Ti-O2} of RT-phase SrTiO₃ similar to those of BaTiO₃ in Fig. 6(a). In addition, ρ of BaTiO₃ at $u_{ext} = 0$ resembles ρ of RT-phase SrTiO₃ at $u_{ext} = -0.01$ (Figs 2(a) and 2(h)), which is consistent with P_S of RT-phase SrTiO₃ at $u_{ext} = -0.01$ similar to P_S of BaTiO₃ at $u_{ext} = 0$ in Fig. 3(a)) and ref. [9] (both by PBEsol). However, the difference between BaTiO₃ and SrTiO₃ still exists at low ρ 's in Figs. 2(d) and 2(k).

In Fig. 3(a), the $P_{\rm S}$ - $u_{\rm ext}$ curves of RT-phase SrTiO₃ exhibit wide variations depending on XC functional. The displacements of Ti, O1 and O2 atom from cubic positions along c-axis of pseudo-cubic 5-atom unit cell in fractions of the c lattice constant ~ 4Å are denoted by $\Delta z_{\rm Ti}$, $\Delta z_{\rm O1}$, and $\Delta z_{\rm O2}$, respectively (Table 2), and $\Delta z_{\rm Ti-O2} = \Delta z_{\rm Ti} - \Delta z_{\rm O2}$ and $\Delta z_{\rm Ti-O1} = \Delta z_{\rm Ti} - \Delta z_{\rm O1}$. Throughout the present paper, we use the coordinate system in which Ba or Sr atom is always fixed at the origin (0, 0, 0) in both paraelectric and ferroelectric phase. For example, the z coordinate of Ti ion is in paraelectric (O_h¹, P4mmm) and ferroelectric phases (C_{4v}¹) are 0.5 and 0.5 + $\Delta z_{\rm Ti}$, respectively (Table 2).

In Fig. 3(b), the ionic displacements (Δz_{Ti} , Δz_{O2} , Δz_{Ti-O2}) vs. u_{ext} curves depend critically on XC functionals but correspond excellently to the P_{S^-} u_{ext} curves of each XC functional. Similar results were found for BaTiO₃ [9]. This suggests that these ion displacements can be good representations for P_{S^-} .

In agreement with established knowledge, c/a, c-lattice constant, and Δz_{Ti} of BaTiO₃ correlated with P_{S} in ref. [9]. In RT- and low-T phase SrTiO₃, on the contrary, the correlations of P_{S} with c/a, c and Δz_{Ti} are ambiguous and are scattered by XC functional dependence in Figs. 4 and 5(a). Therefore, c/a, c-lattice constant, and Δz_{Ti} are not the primary crystallographic parameter responsible for P_{S} of SrTiO₃ (Nonetheless, the c-lattice constant in the limited range > 0.392 nm can be used to estimate P_{S} of SrTiO₃ very approximately).

In Figs. 5(b) and 5(c), both oxygen ion displacements Δz_{O1} and Δz_{O2} correlated with P_S markedly better than Δz_{Ti} . In Fig. 5(b), the P_S - Δz_{O1} plots of BaTiO₃ and RT- and low-T phase SrTiO₃ lie mostly on a single curve. Especially, the plots of P_S - Δz_{O1} of RT- and low-T phase SrTiO₃ lie on a straight line. In Fig. 5(c), the plots of P_S - Δz_{O2} of BaTiO₃ lie on a single curve, while the plots of RT- and low-T phase SrTiO₃ lie excellently on another single line. This indicates that Δz_{O2} is an essential part of the primary crystallographic property for P_S and can be used for the estimation of P_S .

In Fig. 6(a), all the P_S - Δz_{Ti-O2} plots lie on a single straight line, despite the difference in XC functionals, the magnitude of strain, AFD rotation angle φ , lattice, symmetry, and material. In addition, all the P_S - Δz_{Ti-O1} plots lie almost on a single curve in Fig. 6(b). Therefore, Δz_{Ti-O2} and Δz_{Ti-O1} are primary crystallographic properties for P_S . These correlations yield analytical formulas of P_S expressed by Δz_{Ti-O2} or Δz_{Ti-O1} , which is summarized in Table 4. Almost the same results as Figs. 5 and 6 were obtained changing the unit of the displacements, e.g., Δz_{Ti-O2} from fraction of c-lattice constant to absolute value (Å).

As mentioned above, the ground state electron density ρ is determined from the ion positions. Therefore, even when we claim that P_S is determined by the displacement of some ions, the origin of P_S is still ion and electrons. Under this presumption, the ferroelectricity of BaTiO₃ and SrTiO₃ is considered as oxygen-driven, because P_S correlated excellently with Δz_{O2} and Δz_{Ti-O2} and the main contribution to Δz_{Ti-O2} is from Δz_{O2} . This is mainly due to the value of $|\Delta z_{O2}|$ and $|\Delta z_{O1}|$ far larger than Δz_{Ti} as seen in Fig. 5.

The oxygen mechanism is considered more dominant in SrTiO₃ than in BaTiO₃, because P_S correlated with Δz_{O2} and Δz_{O1} better in SrTiO₃ than BaTiO₃ and correlated with Δz_{Ti} worse in SrTiO₃ than BaTiO₃ (Figs. 5(b) and 5(c)). In terms of Γ 15 zone-center phonon of cubic lattice, the present displacement patterns were equal to a mixture of Slater, Last and Axe modes [3-5], whereas the weight of Slater mode was larger in BaTiO₃ than the others, and the weight of each mode was nearly the same in the ferroelectricity of SrTiO₃.

In Figs. 5 and 6, the results for SrTiO₃ and BaTiO₃ at $u_{\text{ext}} = -0.03$ and -0.04, which are shown by small filled red circles and small half-filled brown circles, respectively, exhibit the u_{ext} -dependence different from those for $|u_{\text{ext}}| \leq 0.02$. Here, the growth of SrTiO₃ and BaTiO₃ at $u_{\text{ext}} \leq -0.03$ without defects is experimentally difficult. Indeed, Fig. 3(b) suggests that the strain dependence of Δz_{Ti} , Δz_{O2} and, $\Delta z_{\text{Ti-O2}}$ changes for $u_{\text{ext}} \leq -0.03$; for example, Δz_{Ti} decreased with $|u_{\text{ext}}| \geq 0.03$ in Fig. 3(b). In addition, the unit cell volume increased with $|u_{\text{ext}}| \geq 0.03$, while it decreased with $|u_{\text{ext}}| \leq 0.02$. These characteristics were also found in BaTiO₃ [9]. Therefore, SrTiO₃ and BaTiO₃ for $u_{\text{ext}} \leq -0.03$ are not included in the fitting.

4. Validity of the present formulas

Among the formulas obtained in Sec. 3, the formulas based on $\Delta z_{\text{Ti-O2}}$ and $\Delta z_{\text{Ti-O1}}$ were accurate, while

the formula based on Δz_{O2} was also accurate when different formulas are used for SrTiO₃ and BaTiO₃. Because the formulas based on Δz_{Ti-O2} and Δz_{Ti-O1} work for both SrTiO₃ and BaTiO₃, the validity of the following formulas (Table 4) are examined with experimental values and *ab initio* calculations:

$$P_{\rm S}(\mu \text{C/cm}^2) = 977 \Delta z_{\text{Ti-O2}} + 0.04,$$
 (1)

$$P_{\rm S} (\mu \text{C/cm}^2) = 867 \Delta z_{\text{Ti-O1}} - 2730 \Delta^2 z_{\text{Ti-O1}} + 0.82$$
 (2)

Because Eqs. (1) and (2) use $\Delta z_{\text{Ti-O2}}$ and $\Delta z_{\text{Ti-O1}}$, respectively, we define an oxygen position using "O*": O* in $\Delta z_{\text{Ti-O2}}$ (O*) is an O on a Ti-O bonding perpendicular to the direction of a P_{S} component, and O* in $\Delta z_{\text{Ti-O1}}$ is an O on a Ti-O bonding along a P_{S} component. For example, O* of $\Delta z_{\text{Ti-O2}}$ is O2 of Fig. 1(a) for P_{S} // [001]_{pc} and O1 of Fig. 1(a) for P_{S} // [110]_{pc}.

When the unitcell consists of multiple pseudo cubic cells as in BaSrTi₂O₆ and low-T phase SrTiO₃ in Fig. 7, P_S is defined as an average of all the pseudo cubic cells. When P_S // [001]_{pc} ("pc" stands for pseudo cubic),

 $\Delta z_{\text{Ti-O2}} = \text{distance between Ti and O* ion (Å)} \div c\text{-lattice constant of pseudo cubic 5-atom cell (Å)}.$

For simplicity, the c-lattice constant of pseudo cubic cells can be approximated by an average of all the pseudo cubic cells: For example, the c-lattice constant of pseudo cubic cells in BaSrTi₂O₆ is a half of the c-lattice constant of BaSrTi₂O₆.

Using these definitions, we examine the $P_{\rm S}$ obtained by Eqs. (1) and (2). The first comparison is that with experiments: In Fig. 7, the two black squares represent the comparison between experimental $P_{\rm S}$ of BaTiO₃ [28] and $P_{\rm S}$ estimated by Eqs. (1) and (2) using experimental $\Delta z_{\rm Ti-O2}$ and $\Delta z_{\rm Ti-O1}$ of BaTiO₃ [27].

The second comparison is the validity for the alloys of BaTiO₃ and SrTiO₃ (CaTiO₃): The two red circles represent the comparison of *ab initio* P_S of BaSrTi₂O₆ with P_S estimated by Eqs. (1) and (2) using *ab initio* Δz_{Ti-O2} and Δz_{Ti-O3} of BaSrTi₂O₆. Similarly, the comparisons of Ba₂SrTi₃O₉ and BaCaSrTi₃O₉ are shown.

The third comparison in Fig. 7 is the validity for P_S // a-axis in the unit cell of $Sr_4Ti_4O_{12}$, where O2's on the diagonal positions (illustration of Fig. 7) are rotating around the Ti-O1 axis, i.e., c-axis. In this case, we assumed O* as O1 of Fig. 1(a), i.e. oxygens above and below Ti in the green-framed illustration of Fig. 7. The green diamond in Fig. 7 represents the comparison between ab initio P_S and P_S estimated by Eqs. (1) and

(2) using ab initio $\Delta z_{\text{Ti-O2}}$. All the three comparisons confirm the validity of Eqs. (1) and (2).

The variation of local P_S within parallel and headon domains of BaTiO₃ is shown in Figs. 8(a) and 8(b), where the local P_S 's were estimated by Eqs. (1) and (2) and *ab initio* calculations of extracted 5-atom unitcells like Fig. 1(a). The distribution of local P_S in the parallel domains agreed with literature [29, 30]. $\Delta z_{\text{Ti-O2}}$ and $\Delta z_{\text{Ti-O1}}$ used in Eqs. (1) and (2) was those of the extracted 5-atom unitcells. The z-axis is along c-axis, and the parallel domain runs along x-axis (a-axis). In both types of domains, local P_S 's by Eqs. (1) and (2) agreed excellently with local P_S 's by ab initio calculation. In addition, small x-components of P_S (P_{Sx}) existed in parallel domain, and local P_{Sx} 's by ab initio calculation and Eqs. (1) and (2) agreed mutually. Headon domains like Fig. 8(b) were conventionally unstable but predicted to exist even in the absence of defects owing to the formation of free electron/hole layers [31, 32], of which experiments are recently frequently reported.

5. Summary

The data sets of P_S vs. crystallographic parameters of BaTiO₃ and SrTiO₃ under various conditions calculated with different XC functionals were found to lie precisely on a single curve (Figs. 5(b), 5(c) and 6), despite the wide variations of these data (Fig. 3). Here, the origin of these variations of P_S was found due to the variations of crystallographic parameters. Because such variations of crystallographic parameters were expected to exist in experiments, the parameters' theoretical variations were regarded as the experimental ones. These considerations have yielded empirical analytical formulas of P_S by Δz_{Ti-O2} , Δz_{Ti-O1} , Δz_{O2} , and Δz_{O1} (Table 4), where Δz_{O1} and so forth are explained in Fig. 1(a) and Table 2.

The parameters that correlated best with $P_{\rm S}$ were $\Delta z_{\rm Ti-O2}$, $\Delta z_{\rm Ti-O1}$, and $\Delta z_{\rm O2}$, suggesting the importance of oxygen position and, hence, requesting accurate detection of oxygen positions. The coefficients in the formulas using these displacements are in Table 4.

The validity of the formulas based on $\Delta z_{\text{Ti-O2}}$ and $\Delta z_{\text{Ti-O1}}$ (Eqs. (1) and (2)) was successfully shown in comparison with experiments at RT, BaTiO₃-SrTiO₃ (-CaTiO₃) alloys, a complicated unit cell (Sr₄Ti₄O₁₂), a parallel domain, and a headon domain. As shown in Fig. 7, the present formulas such as Eq. (1) work for P_{S} at any temperature as long as ion positions such as at that temperature is used. Therefore, ion positions given by various kinds of experiments can be used for the present formulas.

The validity of Eqs. (1) and (2) in application to BaTiO₃-SrTiO₃ alloys shows that Eqs. (1) and (2) are applicable to BaTiO₃-SrTiO₃ systems with good accuracy. However, it did not work for PbTiO₃, where the major difference between PbTiO₃ and BaTiO₃-SrTiO₃ is the bonding of A-site atom with Ti [6]. Therefore, Eqs. (1) and (2) may hold for titanate perovskites in which the bonding between Ti and A-site atom is weak, although the inclusion of Ca may decrease the accuracy of Eqs. (1) and (2).

For an extremely large strain, e.g., $u_{\rm ext} \leq -0.03$ in both BaTiO₃ and SrTiO₃, the correlations between $P_{\rm S}$ and displacements and those between properties and strain changed slightly. In addition, the unitcell volume increased with $|u_{\rm ext}|$ for $u_{\rm ext} \leq -0.03$, while it decreased with $|u_{\rm ext}|$ for $u_{\rm ext} \geq -0.02$. This suggests that BaTiO₃ and SrTiO₃ transforms into new states by an extremely large strain. This view is supported by the sharp enhancement of the bonding between atoms in both BaTiO₃ and SrTiO₃ in the charge density ρ for $u_{\rm ext} \leq -0.03$ (Fig. 2).

The present correlations of P_S with Δz_{O2} and Δz_{O1} far better than those with Δz_{Ti} verifies empirically oxygen-driven ferroelectricity by Bilz et al. [8] for BaTiO₃-SrTiO₃ system, where this mechanism is considered more dominant in SrTiO₃ than in BaTiO₃. Accordingly, the conventional identifier Δz_{Ti} [7] was inaccurate and had possibility to estimate P_S incorrectly. This may be important for delicate cases such as flux-closure domain at strained interface [7]. In addition, the earlier prediction of stable headon domains without aid of defects [31, 32] was confirmed.

Acknowledgement

The author acknowledges useful discussions with Dr. Masao Arai and Prof. P. Blöchl.

Data availability

The raw data required to reproduce these findings cannot be shared at this time as the data also form part of an ongoing study. The processed data required to reproduce these findings cannot be shared at this time as the data also forms part of an ongoing study.

Appendix: How to use the formulas

The formulas in Table 4 are for the case of $P_s \ge 0$. For $P_s < 0$, the sign of A and C should be reversed. Here, the convention of the sign of P_s is such that $P_s > 0$ for Ti -O2 > 0, which may be opposite to the convention of *ab initio* calculations.

These formulas are for P_s in 5-atom unit cell, and the length of the lattice along P_s is unity. In application to ferroelectrics consisting of many unitcells, local P_s , i.e. P_s in each 5-atom unit cell is calculated, and the average of local P_s gives the bulk P_s . For example, local P_s in BaSrTi₂O₆ in Fig. 7 is calculated as follows:

By denoting the z coordinates of Ba, Sr, two Ti's, two O2's and two O1's as zBa, zSr, zTi₁, zTi₂, zO2₁, zO2₂, zO1_{Ba} and zO1_{Sr}, respectively,

$$\Delta z_{\text{Ti-O2}} = (z\text{Ti}_1 - z\text{O2}_1)/(z\text{Sr} - z\text{Ba})$$
 and

$$\Delta z_{\text{Ti-O2}} = (z\text{Ti}_2 - z\text{O2}_2)/(z\text{Ba*} - z\text{Sr}),$$

where $zBa^*=1$ and zBa=0. Here, Ti-O2 distance is normalized by the local c lattice constants zSr-zBa or zBa^*-zSr . Alternatively, we may *approximate* $(zSr-zBa) \approx (zBa^*-zSr) \approx c^{BST}/2$, where c is the c lattice constant of BaSrTi₂O₆. Similarly, by noting that the distance between Ti and O1 in paraelectric phase is 0.5,

$$\varDelta \textbf{z}_{r_{i\text{-}O1}} = (zTi_1 - zO1_{Ba})/(zSr - zBa) - 0.5$$
 and

$$\Delta z_{\text{Ti-O1}} = (z\text{Ti}_2 - z\text{O1}_{\text{Sr}})/(z\text{Ba*} - z\text{Sr}) - 0.5.$$

Local P_s is obtained by the substitutions of these $\Delta \mathbf{z}_{\text{Ti-O2}}$ and $\Delta \mathbf{z}_{\text{Ti-O1}}$ into Eqs. (1) and (2). For general case of P_s // layer-direction, e.g., headon domain (Fig. 8(b)),

$$\Delta \mathbf{z}_{\text{Ti-O2}}^{\ \ k} = (z\text{Ti}^{k} - z\text{O2}^{k})/(z\text{A}^{k+1} - z\text{A}^{k})$$
 and

$$\Delta \mathbf{z}_{\text{TSO}}^{k} = (z\text{Ti}^{k} - z\text{O1}^{k})/(z\text{A}^{k+1} - z\text{A}^{k}) - 0.5,$$

where zA^k is the z coordinate of A-site ion in the k^{th} unit cell. For general case of $P_s \perp$ layer-direction, e.g., parallel domain (Fig. 8(a))

$$\Delta \mathbf{z}_{\text{Ti-O2}}^{k} = (z\text{Ti}^{k} - z\text{O2}^{k})$$
 and

$$\Delta \mathbf{z}_{\text{Ti-O1}}^{k} = (z\text{Ti}^{k} - z\text{O1}^{k}) - 0.5.$$

Alternatively, we may approximate $zA^{k+1} - zA^k \approx c^{TOT}/n$ except for the surfaces, where c^{TOT} is the total c lattice constant of the system, i.e., supercell and n is the number of 5-atom unitcells in the supercell.

In applications of these formulas, especially to materials that are not $BaTiO_3$ - $SrTiO_3$, the user should test them by comparing a few P_s 's given by the formulas with those given by the other methods such as experiments or Berry phase calculations.

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Table Captions

Table 1.

Symmetry of SrTiO₃ and BaTiO₃ studied in the present work. The calculated SrTiO₃ phases are cubic (O_h^{-1}) , tetragonal having P_S // c $(C_{4v}^{-1}, D_{4h}^{-1}, D_{4h}^{-18}, and C_{4v}^{-10})$, and orthorhombic (C_{2v}^{-22}) . The calculated BaTiO₃ phases are tetragonal having P_S // c (C_{4v}^{-1}) . In the experiments at RT, SrTiO₃ is O_h^{-1} under stress-free condition and is D_{4h}^{-1} or C_{4v}^{-1} under biaxial strain. The low-T SrTiO₃ is D_{4h}^{-18} in stress-free experiments. The low-T SrTiO₃ with P_S // c and P_S // a_t are C_{4v}^{-10} and C_{2v}^{-22} , respectively, where a_t is an a-axis of 20-atom tetragonal cell.

Table 2.

Atom positions in unitcells of paraelectric cubic (O_h^{-1}) SrTiO₃ and ferroelectric tetragonal $(C_{4v}^{-1}(P4mm))$ BaTiO₃ and SrTiO₃ that have P_S // c. In Figs. 2-6, P_S // c. Ba or Sr atom is always fixed at (0, 0, 0) in both paraelectric and ferroelectric phase. The unit is a = c = 1, where a and c are the a and c lattice constant of the unitcell, respectively. The displacements Δ_{ZTi} , Δ_{ZO1} and Δ_{ZO2} shown by the arrows in Fig. 1(a) are measured from cubic position of each ion along c-axes (z-axis) in fractions of the c lattice constant. O1 and O2 are defined in Fig. 1(a). In pseudo cubic unitcell representations of low-T phase SrTiO₃, the z-coordinates of atoms of paraelectric (D_{4h}^{-18}) and ferroelectric $(C_{4v}^{-10}(I4cm))$ that has P_S // c are similar to those of the paraelectric and ferroelectric in Table 2, respectively.

Table 3.

List of exchange correlation (XC) functionals used in this work. However, it is unnecessary to know which XC functional was used in Figs. 2-8. "_LT" shows the calculations of low-*T* phase SrTiO₃, whereas those without "_LT" are for the RT-phase.

Table 4.

Coefficients of fittings to *ab initio* results. R^2 and σ stand for the coefficient of determination and the standard deviation, respectively. These formulas are for the case of $P_s \ge 0$. "How to use the formulas" is explained in Appendix.

Figure captions

- **Fig. 1.** (a) Unit cell consisting of 5 atoms, while green spheres, light blue spheres, and red spheres represent Ba(Sr), Ti and O ions, respectively. The coordinates are defined such that x, y and z-axis are along the a-, a- and c-axis of the unitcell, respectively. (b) Unit cell consisting of 20 atoms of low-T phase of SrTiO₃ viewed along c-axis (top view), where the orange frame shows pseudo cubic unit cell of 5 atoms.
- Fig. 2. Calculated valence electron density ρ of ground state of (a)-(f) tetragonal BaTiO₃ and (g)-(l) RT-phase SrTiO₃ with $P_S > 0$ under strain-free and strained condition, where the value of external strain $u_{\rm ext}$ is shown on the left. (a)-(c) [100] and (d)-(f) [110] planes of BaTiO₃. (g)-(i) [100] and (j)-(l) [110] plane of SrTiO₃. The first row: (a), (d), (g) and (j) is for $u_{\rm ext} = 0$, the second row: (b), (e), (h) and (k) is for $u_{\rm ext} = -0.01$, and the third row (c), (f), (i) and (l) is for $u_{\rm ext} = -0.04$. The calculation for cubic SrTiO₃ is shown in (g) and (j), but the calculations with some XC functionals show the existence of P_S for $u_{\rm ext} = 0$ [25]. The red color represents $\rho > 0.5 \ e/Å^3$ in the [100] planes ((a)-(c) and (g)-(i)) and $\rho > 0.1 \ e/Å^3$ in the [110] planes ((d)-(f) and (j)-(l)), and ρ decreases in the order of red, yellow, green, and blue. The positions of ions are shown by letters, where O1 and O2 are oxygen in BaO (SrO) and TiO2 layer, respectively (Fig. 1(a)).
- Fig. 3. (a) External biaxial inplane strain ($u_{\rm ext}$) dependence of $P_{\rm S}$ of RT-phase SrTiO₃. Both large and small filled red circles, filled green diamonds, half-filled green diamonds, and light blue squares represent the results of PBEsol, HSE, HSEsol, and LDA for RT-phase SrTiO₃, respectively. This convention of symbols is kept throughout the present paper. (b) Displacements of Ti and O2 atom from cubic positions along c-axis (z-axis) ($\Delta z_{\rm Ti}$, $\Delta z_{\rm O2}$) and difference of them ($\Delta z_{\rm Ti-O2}$) in fractions of the c lattice constant (Table 2) are plotted against $u_{\rm ext}$. The small symbols represent $\Delta z_{\rm Ti}$.
- **Fig. 4.** (a) P_S vs. c/a and (b) P_S vs. c lattice constant for stress-free and strained RT- and low-T phase SrTiO₃. Solid lines are fittings to the results given by HSE. The meanings of other symbols are same as in Fig. 3. In addition, filled pink circles and filled dark blue diamonds represent the results of PBEsol and HSE results for low-T phase SrTiO₃, respectively, where "_LT" in legends stands for "low-T"(Table 3).
- **Fig. 5.** Correlation of P_S with atomic displacements (a) Δz_{Ti} of stress-free and strained RT- and low-T phase SrTiO₃. Correlation of P_S with (b) Δz_{O1} and (c) Δz_{O2} of stress-free and strained BaTiO₃ and RT- and

low-T phase SrTiO₃. Δz_{Ti} , Δz_{O1} and Δz_{O2} are defined in Table 2 and shown by the arrows in of Fig. 1(a). The distinction of XC functionals shown by symbols in the legends is unnecessary: Filled red circles, filled green diamonds, half-filled green diamonds, and light blue squares represent the results of PBEsol, HSE, HSEsol, and LDA for RT-phase SrTiO₃, respectively. Filled pink circles and filled dark blue diamonds represent the results for low-T phase SrTiO₃. Half-filled brown circles, half-filled dark green diamonds, small half-filled dark green diamonds, small filled violet squares, filled blue triangle, and filled inverted blue triangle represent the results of PBEsol, HSEsol, HSE, LDA, TPSS, and TPSS+U for BaTiO₃, respectively. In Figs. 5 and 6, the results at $u_{\text{ext}} = -0.03$ and -0.04 (PBEsol) are shown by small filled red circles and small half-filled brown circles, which were not used in the fittings. In (b), solid orange lines are fitting (Table 4). In (c), solid dark yellow and orange lines are 2^{nd} and 3^{rd} order polynomial fittings to all the BaTiO₃ data, respectively, while solid violet lines are fitting to SrTiO₃ data.

Fig. 6. Correlation of P_S with (a) Δz_{Ti-O2} and (b) Δz_{Ti-O1} of stress-free and strained BaTiO₃ and RT- and low-T phase SrTiO₃. Δz_{Ti-O2} and Δz_{Ti-O1} are the difference between Δz_{Ti} and Δz_{O2} and that between Δz_{Ti} and Δz_{O1} , respectively. The meanings of the symbols are the same as those in Fig. 5, but the distinction of XC functionals is unnecessary. In (a), the solid orange and dashed black lines are fitting to all the data and BaTiO₃ data, respectively (Table 4). In (b), solid dark yellow and orange lines are 2^{nd} and 3^{rd} order polynomial fittings to all data, respectively, while dashed black lines are fitting to BaTiO₃ data.

Fig. 7. Comparison of macroscopic P_S estimated by Eqs. (1) and (2) with experimental and *ab initio* P_S of bulk materials: BaTiO₃ (experiments of P_S at 298 K [27] and Δz_{Ti-O2} and Δz_{Ti-O1} at 303 K [28]), black squares), BaSrTi₂O₆ (*ab initio*, red circles), Ba₂SrTi₃O₉ (*ab initio*, pink hexagons), BaCaSrTi₃O₉ (*ab initio*, light blue star), low-T phase tetragonal SrTiO₃ with P_S along [100] (*ab initio*, green diamond). The filled and open symbols represent the results by Eqs. (1) and (2), respectively. The solid lines show the curve for " P_S by experiments or *ab initio* calculation = P_S by the formula"; all the symbols should be on this line, when the estimations by the formula are perfectly accurate. The illustrations in red, pink, light blue and green frame show side views of BaSrTi₂O₆, Ba₂SrTi₃O₉ and BaCaSrTi₃O₉, and a top view of SrTiO₃ unit cell consisting of 25 atoms, respectively. In each illustration, green spheres, dark green spheres, blueish green spheres, light blue spheres, and red spheres represent Ba, Sr, Ca, Ti and O ions, respectively, and the

black arrow shows the direction of P_S .

Fig. 8. Estimations of atomic-scale, i.e., local P_S . (a) parallel, i.e. cc domain running in the direction of a-axis (x), where the entire upward and downward domain consist of 16 unitcell (80 atoms). Filled black squares, filled red circles, open pink circles represent P_S component along c-axis (z) estimated by ab initio calculation, Eq. (1), and Eq. (2), respectively. Filled green squares, filled blue circles, and open light blue circles represent P_S component along a-axis estimated by ab initio calculation, Eq. (1), and Eq. (2), respectively. (b) Headon, i.e. encountering domain running in the direction of c-axis (z), where the entire upward and downward domain consist of 20 unitcell (100 atoms). Filled black squares, filled blue circles, and open green circles represent P_S estimated by ab initio calculation, Eq. (1), and Eq. (2), respectively.

Table 1

SrTiO ₃	paraelectric	ferroelectric $P_{\rm S}$ // c	ferroelectric $P_{\rm S}$ // a	
RT-phase	O_h^{-1} (Pm3m)	C _{4v} ¹ (P4mm)		
	$(D_{4h}^{-1}(P4mmm))$			
low-T-phase	D _{4h} ¹⁸ (I4mcm)	C _{4v} ¹⁰ (I4cm)	C _{2v} ²² (Ima2m)	
RT-BaTiO ₃		C _{4v} ¹ (P4mm)		

Table 2

	Paraelectric (O _h ¹ , D _{4h} ¹)	Ferroelectric (C _{4v} ¹)		
Ba, Sr	(0, 0, 0)	(0,0,0)		
Ti	(0.5, 0.5, 0.5)	$(0.5, 0.5, 0.5 + \Delta z_{Ti})$		
O1	(0.5, 0.5, 0)	$(0.5, 0.5, 0 + \Delta z_{O1})$		
O2	(0, 0.5, 0.5)	$(0, 0.5, 0.5 + \Delta z_{O2})$		
O2	(0.5, 0, 0.5)	$(0, 0.5, 0.5 + \Delta z_{O2})$		

Table 3

name	description		
LDA	Local density approximation		
PBEsol	Perdew-Burke-Ernzerhof functional for solids [13]		
TPSS	Tao-Perdew-Staroverov-Scuseria functional [14,15]		
HSE	Heyd-Scuseria-Ernzerhof functional (HSE06) [16,18]		
HSEsol	HSE for solid [17]		
TPSS + U	TPSS with Hubbard-like local potential [19]		

PBEsol_LT	PBEsol calculation of low-T SrTiO ₃ : Figs.4-6				
HSE_LT	HSE calculation of low-T SrTiO ₃	: Figs.4-6			

Table 4

$P_{s}(\mu C/cm^{2}) = A+Bx+Cx^{2}+Dx^{3}$		Х	A	В	С	D	R^2	σ
Fig.5(b)	All	$\Delta z_{_{\mathrm{O}1}}$	-0.77	-1670	-22600	-106000	0.982	0.0025
Fig.5(c)	BTO	$arDelta oldsymbol{z}_{\!\scriptscriptstyle{\mathrm{O}2}}$	0.01	-2280	-22700	0	0.999	0.0050
	BTO	$arDelta oldsymbol{z}_{_{\mathrm{O}2}}$	-0.01	-2500	-39700	-313000	0.999	0.0070
	STO	$\Delta z_{_{ m O2}}$	0.29	-1040	0	0	0.997	0.0007
	STO	$arDelta oldsymbol{z}_{\!\scriptscriptstyle{\mathrm{O}2}}$	0.05	-1130	-3230	0	0.996	0.0007
Fig.6(a)	ВТО	$\Delta \mathbf{Z}_{ ext{Ti-O2}}$	0.04	977	0	0	1.000	0.0045
	STO	$\Delta Z_{ ext{Ti-O2}}$	-0.05	926	0	0	0.999	0.0004
	All	$\Delta z_{ ext{Ti-O2}}$	-0.02	959	0	0	0.999	0.0098
Fig.6(b)	ВТО	$\Delta z_{ ext{\tiny Ti-Ol}}$	8.52	549	0	0	0.988	0.0101
	ВТО	$\Delta z_{ ext{Ti-Ol}}$	0.01	851	-2560	0	0.999	0.0063
	STO	$\Delta z_{ ext{ in-ol}}$	0.27	954	0	0	0.995	0.0010
	All	$\Delta Z_{\text{Ti-Ol}}$	0.82	867	-2730	0	0.989	0.0185
	All	$\Delta Z_{ ext{Ti-Ol}}$	-0.23	1190	-13100	81700	0.994	0.0129

Fig.1

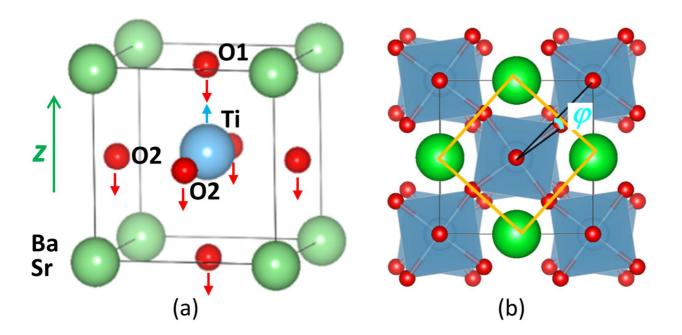


Fig.2

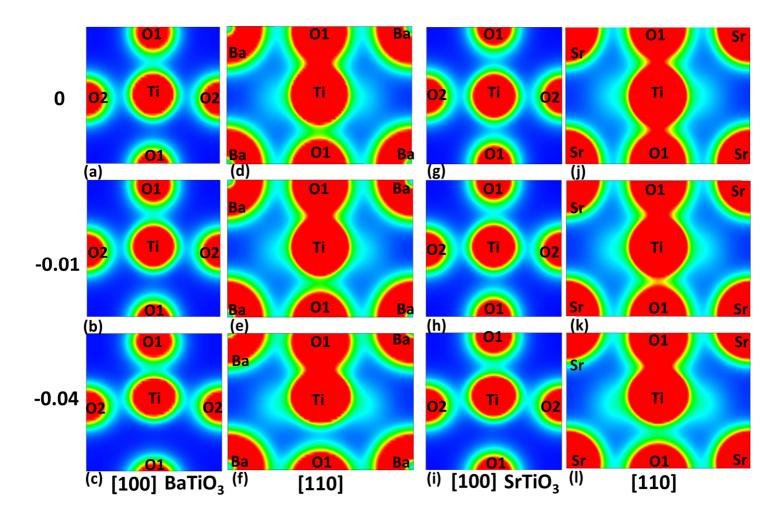


Fig.3

